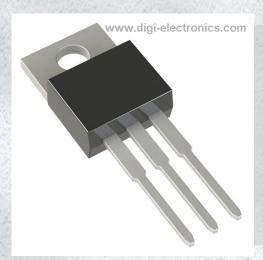


## **IXTP8N50P Datasheet**



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXTP8N50P-DG

Manufacturer IXYS

Manufacturer Product Number IXTP8N50P

Description MOSFET N-CH 500V 8A TO220AB

Detailed Description N-Channel 500 V 8A (Tc) 150W (Tc) Through Hole T

0-220-3



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RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXTP8N50P	IXYS
Series:	Product Status:
PolarHV™	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
500 V	8A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	800mOhm @ 4A, 10V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
5.5V @ 100μA	20 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	1050 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	150W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-220-3	TO-220-3
Base Product Number:	
IYTDQ	

## **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.29.0095



## **OUR CERTIFICATE**

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